

Transistors

TO-92L • TO-92LS • MRT

TO-92L is a high power version of TO-92 and TO-92LS is a slimmed TO-92L.

MRT is a 1.2W package power taped transistor designed for use with an automatic placement machine.

Application	Package			V _{CEO} (V) *V _{CEB}	I _C (A)	I _C Max. (A)	P _C (W) (T _a =25°C)			h _{FE}	h _{FE} Rating ext.	V _{CE} (V)	I _C (mA)	Internal circuit
	TO-92L	TO-92LS	MRT				TO-92L	TO-92LS	MRT					
	Part No.													
Low Noise	—	2SA1819	—	-150	-0.05	—	—	0.8	—	120~390	Q R	-6	-2	—
	—	2SC4720	—	-150	0.05	—	—	0.8	—	120~390	Q R	6	2	—
Driver	2SA934	2SA1818	2SB1329	-32	-1	-2	0.75	0.9	1.2	82~390	P Q R	-3	-100	—
	2SA935	2SA1902	2SB1330	-80	-0.7	—	0.75	0.9	1.2	82~390	P Q R	-3	-100	—
	2SB1010	2SB1595	2SB1331	-32	-2	-3	0.75	0.9	1.2	82~390	P Q R	-3	-500	—
	2SB1041	—	2SB1332	-80	-1	—	0.9	—	1.2	82~390	P Q R	-3	-100	—
	2SB1043	—	—	-80	-1	—	0.9	—	—	82~390	P Q R	-3	-100	—
	2SB1212	2SB1596	2SB1328	-180	-1.5	—	0.9	0.9	1.2	56~270	N P Q	-5	-100	—
	2SB1425	—	—	-20	-2	-3	1.0	—	—	270~1200	S E U	-6	-500	—
	—	—	2SB1517	-50	-3	—	—	—	1.2	56~390	N P Q R	-3	-500	—
	2SC2060	2SC4719	2SD2005	32	1	2	0.75	0.9	1.2	82~390	P Q R	3	100	—
	2SC2061	2SC5061	2SD2006	80	0.7	1	0.75	0.9	1.2	82~390	P Q R	3	100	—
	2SD1292	—	2SD2008	80	1	2	0.9	—	1.2	82~390	P Q R	3	500	—
	2SD1384	2SD2450	2SD2007	32	2	2.5	0.75	0.9	1.2	82~390	P Q R	3	900	—
	2SD1812	2SD2451	2SD2004	180	1.5	—	0.9	0.9	1.2	56~270	N P Q	5	100	—
	—	—	2SD2146	50	3	—	—	—	1.2	56~390	N P Q R	3	500	—
Low V _{CE(sat)}	—	2SA1903	—	-20	-3	—	—	0.9	—	82~390	P Q R	-2	-100	—
	2SB1374	2SA1820	—	-50	-2	-5	1.0	0.9	—	82~270	P Q	-2	-500	—
	—	2SC5062	—	20	3	—	—	0.9	—	120~560	Q R S	2	100	—
2SD2069	2SC4721	—	50	2	5	1.0	0.9	—	82~270	P Q	2	500	—	
Strobe Flash Low V _{CE(sat)}	2SB1306	—	2SB1482	-20	-5	-10	1.2	—	1.2	82~390	P Q R	-2	-500	—
	2SD1961	—	—	20	5	10	1.2	—	—	120~560	Q R S	2	500	—
Chrome	2SC3259	2SC4722	2SC4243	300	0.1	—	0.75	0.9	1.0	39~180	M N P	10	10	—
High h _{FE}	2SB1425	—	2SB1461	-20	-2	-3	1.0	—	1.2	270~820	S E	-6	-500	—
	2SD2159	—	—	25	2	3	1.0	—	—	390~2700	E U V W	6	500	—
High h _{FE} High V _{CEO}	2SD2172	—	—	25	1.2	2	1	—	—	560~2700	U V W	5	500	—
Darlington	2SB1256	—	2SB1333	-100	-2	—	1.2	—	1.2	1k~10k	—	-2	-1000	Fig.1
	—	—	2SB1515	-80	-4	—	—	—	1.2	1k~10k	—	-3	-2000	Fig.1
	—	—	2SD2452	31±4	2	3	—	—	1.2	1k~10k	—	2	1000	Fig.5
	2SD1809	—	2SD2009	60*	1	—	0.9	—	1.2	2k~	—	3	500	Fig.2
	2SD1929	—	2SD2010	60±10	2	—	1.2	—	1.2	1k~10k	—	2	1000	Fig.5
	2SD1930	—	2SD2011	100	2	—	1.2	—	1.2	1k~10k	—	2	1000	Fig.4
	—	—	2SC4724	100	3	5	—	—	1.2	2k~10k	—	2	1500	Fig.4
	2SD1931	—	—	60±10	1.5	—	0.9	—	—	1k~30k	—	2	1000	Fig.6
	—	—	2SD2308	80	4	—	—	—	1.2	1k~10k	—	3	2000	Fig.4
—	—	2SD2309	60	4	—	—	—	1.2	1k~10k	—	3	2000	Fig.3	
Darlington Driver	—	—	2SD2366	90 ⁺²⁰ ₋₁₀	2	3	—	—	1.2	1k~10k	—	2	1000	Fig.5
High Voltage SW	2SA1684	—	—	-400	-0.1	-0.2	0.9	—	—	56~270	N P Q	-10	-10	—
	2SA1780	2SA1884	2SA1809	-400	-0.5	-1	0.9	0.9	1.2	56~270	N P Q	-5	-50	—
	2SA1760	—	—	-400	-0.1	-0.2	0.9	—	—	56~270	N P Q	-10	-10	—
	—	—	2SA1861	-400	-2	-4	—	—	1.2	56~180	N P	-5	-100	—
	2SC4166	—	—	400	0.1	—	0.9	—	—	56~270	N P Q	10	10	—

Note: *Under development

Darlington transistor internal circuit



